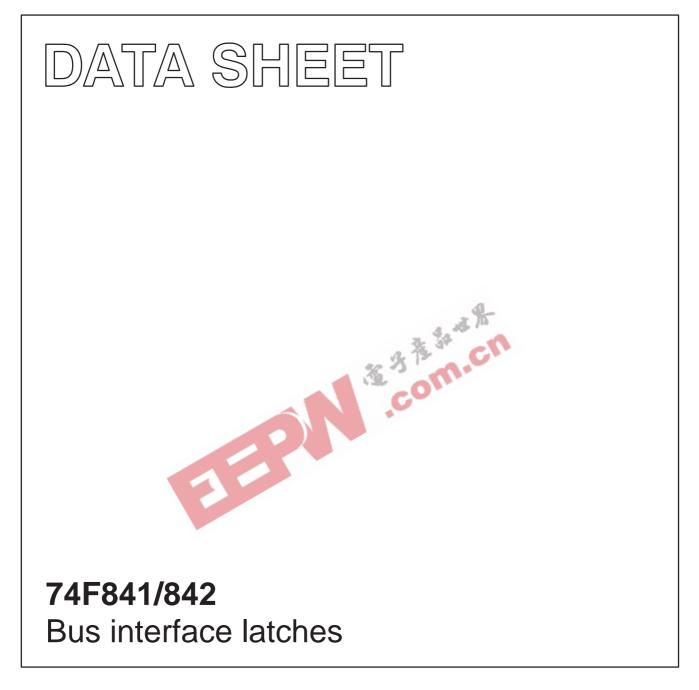
# INTEGRATED CIRCUITS



Product data Replaces datasheet 74F841/842/843/845/846 of 1999 Jun 23 2004 Jan 23



74F841/74F842

#### **FEATURES**

- High speed parallel latches
- Extra data width for wide address/data paths or buses carrying parity
- High impedance NPN base input structure minimizes bus loading
- I<sub>IL</sub> is 20 μA for minimum bus loading
- Buffered control inputs to reduce AC effects
- Ideal where high speed, light loading, or increased fan-in are required as with MOS microprocessors
- · Positive and negative over-shoots are clamped to ground
- 3-State outputs glitch free during power-up and power-down
- 48 mA sink current
- Slim dual in-line 300 mil package
- Broadside pinout

### **ORDERING INFORMATION**

#### DESCRIPTION

The 74F841 and 74F842 bus interface latches are designed to provide extra data width for wider address/data paths of buses carrying parity.

The 74F841 consists of ten D-type latches with 3-State outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition. On the LE HIGH-to-LOW transition, the data that meets the set-up and hold time is latched.

Data appears on the bus when the Output Enable ( $\overline{OE}$ ) is LOW. When  $\overline{OE}$  is HIGH the output is in the high-impedance state.

The 74F842 is the inverted output version of the 74F841.

ТҮРЕ	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)	
74F841, 74F842	5.5 ns	60 mA	

<ul> <li>Broadside pinout</li> </ul>			00 11/1
ORDERING INFORMAT	-	b = 0 °C to +70 °C	
Type number	Package	CO.	
	Name	Description	Version
N74F841N, N74F842N	DIP24	plastic dual in-line package; 24 leads (300 mil)	SOT222-1
N74F841D, N74F842D	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1

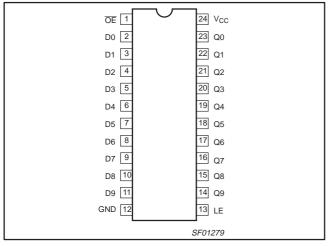
## INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

PINS	DESCRIPTION	74F(U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
Dn	Data inputs	1.0/0.033	20 μΑ / 20 μΑ
LE	Latch Enable input	1.0/0.033	20 μΑ / 20 μΑ
ŌĒ	Output Enable input (active-LOW)	1.0/0.033	20 μΑ / 20 μΑ
Qn	Data outputs	1200/80	24 mA / 48 mA
Qn	Data outputs	1200/80	24 mA / 48 mA

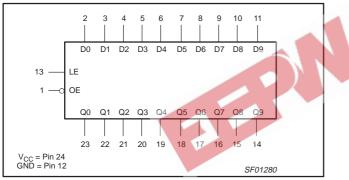
NOTE: One (1.0) FAST Unit Load is defined as: 20 µA in the HIGH state and 0.6 mA in the LOW state.

74F841/74F842

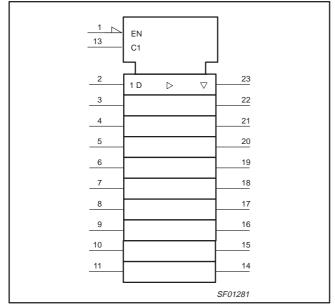
## **PIN CONFIGURATION for 74F841**



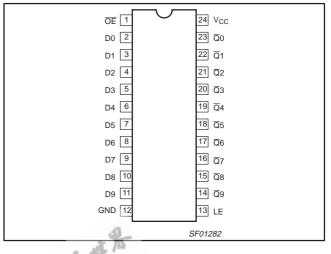
# LOGIC SYMBOL for 74F841



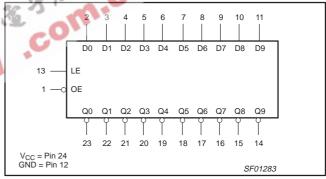
# LOGIC SYMBOL (IEEE/IEC) for 74F841



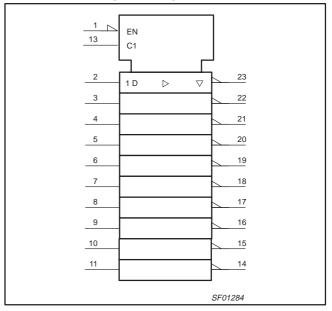
# **PIN CONFIGURATION for 74F842**



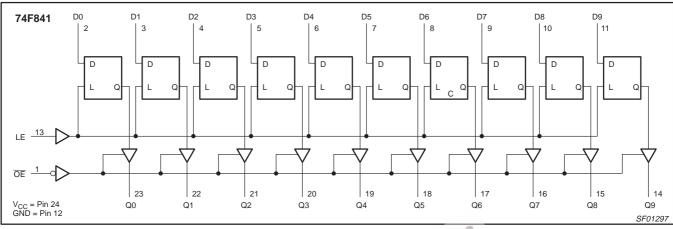
# LOGIC SYMBOL for 74F842



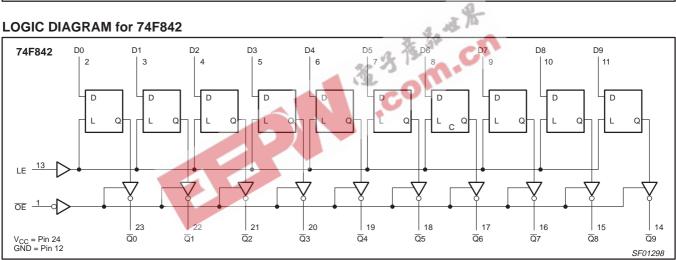
### LOGIC SYMBOL (IEEE/IEC) for 74F842



# LOGIC DIAGRAM for 74F841



# LOGIC DIAGRAM for 74F842



### FUNCTION TABLE for 74F841 and 74F842

	INPUTS		OUTPUTS			
	INFUIS		74F841	74F842	OPERATING MODE	
OE	LE	Dn	Qn	Qn		
L	Н	L	L	Н	Transport	
L	Н	Н	Н	L	Transparent	
L	$\downarrow$	I	L	Н	Latched	
L	$\downarrow$	h	Н	L	Latched	
Н	Х	Х	Z	Z	High Impedance	
L	L	Х	NC	NC	Hold	

HIGH voltage level H = LOW voltage level

L = HIGH state one set-up time before the HIGH-to-LOW LE transition h =

LOW state one set-up time before the HIGH-to-LOW LE transition L =

 $\downarrow$ = HIGH-to-LOW transition

Х = Don't care

NC= No change

Z = High impedance "off" state

# 74F841/74F842

### **ABSOLUTE MAXIMUM RATINGS**

Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.

SYMBOL	PARAMETER	RATING	UNIT
V <sub>CC</sub>	supply voltage	-0.5 to +7.0	V
V <sub>IN</sub>	input voltage	-0.5 to +7.0	V
I <sub>IN</sub>	input current	-30 to +5	mA
V <sub>OUT</sub>	voltage applied to output in HIGH output state	–0.5 to $V_{CC}$	V
I <sub>OUT</sub>	current applied to output in LOW output state	84	mA
T <sub>amb</sub>	operating free-air temperature range	0 to +70	°C
T <sub>stg</sub>	storage temperature range	-65 to +150	°C

#### **RECOMMENDED OPERATING CONDITIONS**

CYMDOL	DADAMETER					
SYMBOL	PARAMETER	MIN	NOM	MAX	UNIT	
V <sub>CC</sub>	supply voltage	27	4.5	5.0	5.5	V
V <sub>IH</sub>	HIGH-level input voltage		2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	C	-	-	0.8	V
I <sub>IK</sub>	input clamp current		-	-	-18	mA
I <sub>ОН</sub>	HIGH-level output current		-	-	-24	mA
I <sub>OL</sub>	LOW-level output current		-	-	48	mA
T <sub>amb</sub>	operating free-air temperature range		0	-	+70	°C

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating free-air temperature range unless otherwise noted.

OVINDO			TEST CONDITIONS <sup>1</sup>			LIMITS		
SYMBOL	PARAMETER					TYP <sup>2</sup>	MAX	UNIT
			15	$\pm 10\% V_{CC}$	2.2	-	-	V
M	HIGH-level output voltage	V <sub>CC</sub> = MIN; V <sub>IL</sub> = MAX;	I <sub>OH</sub> = -15 mA	$\pm$ 5%V <sub>CC</sub>	2.2	3.3	-	V
V <sub>OH</sub>	nigh-level output voltage	$V_{IH} = MIN$	I <sub>OH</sub> = -24 mA	$\pm 10\% V_{CC}$	2.0	-	-	V
			$I_{OH} = -24 \text{ IIIA}$	$\pm 5\% V_{CC}$	2.0	-	-	V
M		V <sub>CC</sub> = MIN; V <sub>IL</sub> = MAX;	I <sub>OL</sub> = 32 mA	$\pm 10\% V_{CC}$	-	0.38	0.55	V
V <sub>OL</sub>	LOW-level output voltage	$V_{IH} = MIN$	I <sub>OL</sub> = 48 mA	$\pm$ 5%V <sub>CC</sub>	-	0.38	0.55	V
V <sub>IK</sub>	Input clamp voltage	V	$_{\rm CC}$ = MIN; $I_{\rm I}$ = $I_{\rm IK}$		-	-0.73	-1.2	V
lı	Input current at maximum input voltage	V <sub>CC</sub>	$V_{CC} = 0 V; V_{I} = 7.0 V$			-	100	μA
I <sub>IH</sub>	HIGH-level input current	V <sub>CC</sub>	= MAX; V <sub>I</sub> = 2.7	V S	-	-	20	μA
IIL	LOW-level input current	$V_{CC} = MAX; V_1 = 0.5 V$				-	-20	μA
I <sub>OZH</sub>	Off-state output current, HIGH-level voltage applied	$V_{CC}$ = MAX; $V_{O}$ = 2.7 V			_	-	50	μA
I <sub>OZL</sub>	Off-state output current, LOW-level voltage applied	V <sub>CC</sub> = MAX; V <sub>O</sub> = 0.5 V		-	-	-50	μA	
I <sub>OS</sub>	Short-circuit output current <sup>3</sup>		$V_{CC} = MAX$		-100	-	-225	mA
	Іссн				-	50	65	mA
	74F841 I <sub>CCL</sub>		$V_{CC} = MAX$		-	60	80	mA
	Supply current				-	70	92	mA
Icc	(total)				-	40	60	mA
	74F842 I <sub>CCL</sub>		$V_{CC} = MAX$		-	65	90	mA
	I <sub>CCZ</sub>	<u> </u>			-	60	90	mA

NOTES:

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

 All typical values are at V<sub>CC</sub> = 5 V, T<sub>amb</sub> = 25 °C.
 Not more than one output should be shorted at a time. For testing I<sub>OS</sub>, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a HIGH output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter test, I<sub>OS</sub> tests should be performed last.

						LIN	IITS			
SYMBOL	PARAMETER		PARAMETER TEST CONDITION		-	$T_{amb}$ = +25 °C V <sub>CC</sub> = +5.0 V C <sub>L</sub> = 50 pF; R <sub>L</sub> = 500 Ω			T <sub>amb</sub> = 0 °C V <sub>CC</sub> = +5. C <sub>L</sub> = 50 pF;	UNIT
				MIN	ТҮР	MAX	MIN	MAX		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay Dn to Qn	74F841	Waveform 1, 2	2.0 2.5	4.0 4.5	7.5 7.5	2.0 2.5	8.0 8.0	ns	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay LE to Qn	746041	Waveform 1, 2	4.5 4.0	6.5 6.0	9.5 9.0	4.0 3.5	10.0 9.5	ns	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay Dn to Qn	74F842	Waveform 1, 2	3.5 3.0	5.5 5.0	8.5 8.0	4.5 4.0	9.0 8.5	ns	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay LE to Qn	74042	Waveform 1, 2	5.0 4.5	7.0 6.5	10.0 9.0	3.0 3.0	10.5 9.5	ns	
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time HIGH or LOW-level OE to Qn	or Qn	Waveform 4 Waveform 5	2.5 4.0	<b>4.5</b> 6.0	8.0 9.5	2.0 3.0	8.5 10.5	ns	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time HIGH or LOW-level OE to Qn	or Qn	Waveform 4 Waveform 5	1.0 1.0	4.5 5.0	8.0 8.0	1.0 1.0	8.5 8.5	ns	

# AC ELECTRICAL CHARACTERISTICS for 74F841/74F842

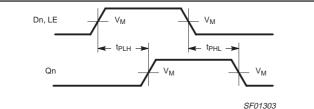
PLZ			Waveloini 5	1.0 5.	.0 0.0	1.0	0.0	
AC SET-l	JP REQUIREMENTS for	74F841/7	4F842	32	m.			
SYMBOL	PARAMETER		TEST	V <sub>CC</sub> =	+25 °C	V <sub>CC</sub> = +5.	C to +70 °C 0 V ± 10% R <sub>L</sub> = 500 Ω	UNIT
				MIN	TYP	MIN	MAX	
t <sub>s</sub> (H) t <sub>s</sub> (L)	Set-up time, HIGH or LOW Dn to LE		Waveform 3	0.0 0.0		1.0 1.0		ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time, HIGH or LOW Dn to LE	74F841	Waveform 3	2.5 3.0		3.0 4.0		ns
t <sub>w</sub> (H)	LE pulse width, HIGH		Waveform 3	3.5	-	4.0	-	ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time, HIGH or LOW Dn to LE	74F842	Waveform 3	3.0 3.5	-	3.5 4.5	-	ns
t <sub>w</sub> (H)	LE pulse width, HIGH		Waveform 3	3.0	-	3.0	-	ns

# 74F841/74F842

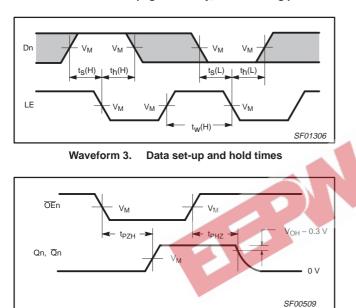
#### AC WAVEFORMS

For all waveforms,  $V_{M} = 1.5$  V.

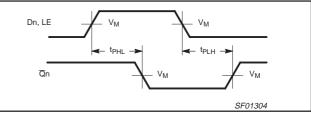
The shaded areas indicate when the input is permitted to change for predictable output performance.



Waveform 1. Propagation delay, non-inverting path

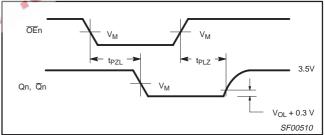


Waveform 4. 3-State Output Enable time to HIGH level and Output Disable time from HIGH level



Waveform 2. Propagation delay, inverting path

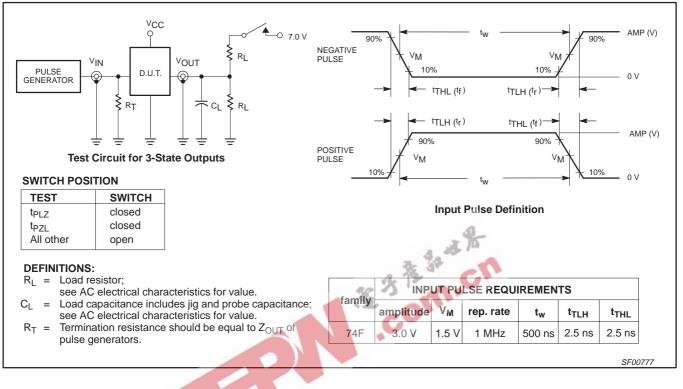


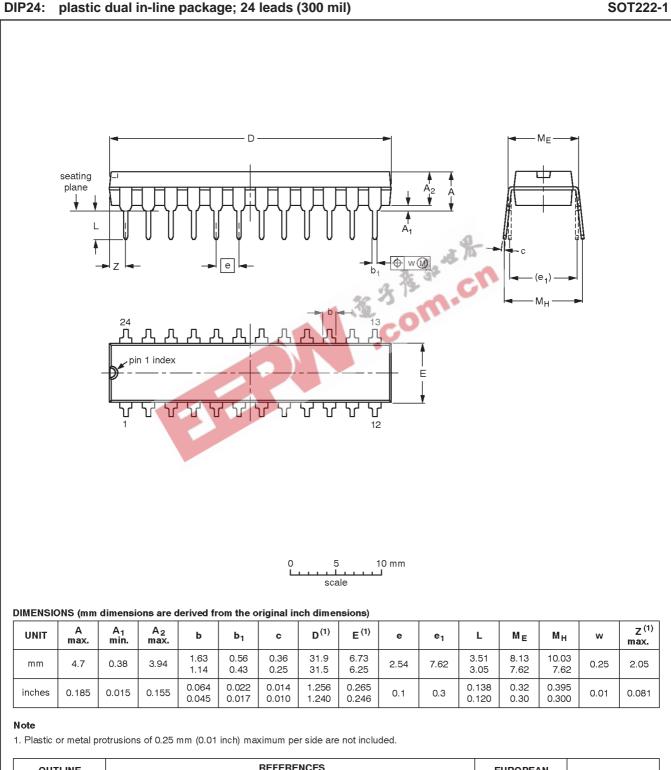


Waveform 5. 3-State Output Enable time to LOW level and Output Disable time from LOW level

74F841/74F842

# **TEST CIRCUIT AND WAVEFORMS**



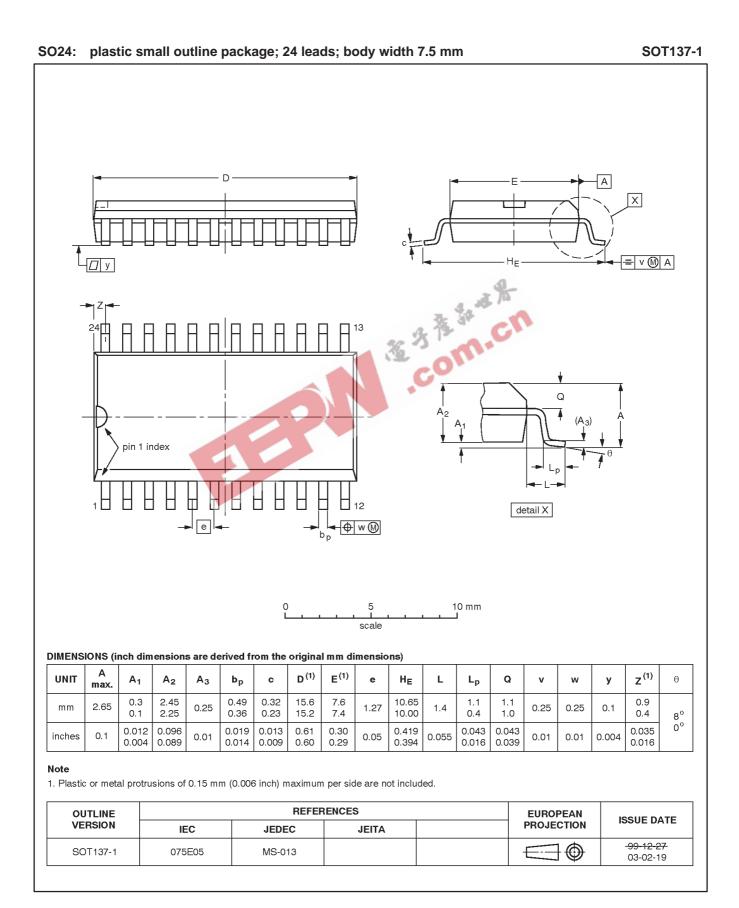


REFERENCES OUTLINE EUROPEAN **ISSUE DATE** VERSION PROJECTION IEC JEDEC JEITA 99-12-27  $\odot$ SOT222-1 MS-001 03-03-12

SOT222-1

74F841/74F842

# 74F841/74F842



#### **REVISION HISTORY**

Rev	Date	Description
_4	20040123	Product data (9397 750 12746). ECN 853-1208 A15379 of 22 January 2004. Replaces Product specification 74F841/842/843/845/846_3 dated 1999 Jun 23 (9397 750 06143).
		Modifications:
		<ul> <li>Delete all references to 74F843, 74F845, 74F846 (products discontinued).</li> </ul>
_3	19990623	Product specification (9397 750 06143). ECN 853-1208 21851 of 23 June 1999. Replaces datasheet 74F841/842/843/844/845/846 of 1999 Jan 08.

#### Data sheet status

Level	Data sheet status <sup>[1]</sup>	Product status <sup>[2] [3]</sup>	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL [2] http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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